



DMT4014LDV

PowerDI3333-8

#### **Product Summary**

BV <sub>DSS</sub>	Rds(on) Max	l⊳ Max Tc = +25°C
	19mΩ @ V <sub>GS</sub> = 10V	26.5A
40V	29mΩ @ V <sub>GS</sub> = 4.5V	21.8A

# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$  yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Wireless Charging
- DC-DC Converters
- Power Management

## Features and Benefits

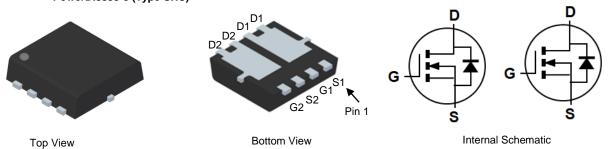
 100% Unclamped Inductive Switching (UIS) Test in Production — Ensures More Reliable and Robust End Application

40V N-CHANNEL ENHANCEMENT MODE MOSFET

- Low R<sub>DS(ON)</sub> Ensures On-State Losses Are Minimized
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

#### **Mechanical Data**

- Case: PowerDI<sup>®</sup>3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.072 grams (Approximate)



## Ordering Information (Note 4)

Part Number	Case	Packaging
DMT4014LDV-7	PowerDI3333-8 (Type UXC)	2,000/Tape & Reel
DMT4014LDV-13	PowerDI3333-8 (Type UXC)	3,000/Tape & Reel

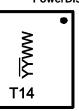
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



PowerDI3333-8 (Type UXC)

 $\frac{T14}{YY} = Product Type Marking Code$   $\frac{YY}{YY} = Date Code Marking$   $\frac{YY}{Y} = Last Two Digits of Year (ex: 20 = 2020)$ WW = Week Code (01 to 53)

### PowerDI3333-8 (Type UXC)



# Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage		V <sub>DSS</sub>	40	V	
Gate-Source Voltage		Vgss	±20	V	
Continuous Drain Current (Note 6) $V_{GS} = 10V$ $T_C = +25^{\circ}C$ $T_C = +70^{\circ}C$			ID	26.5 21.2	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	lo	8.5 6.8	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		Ідм	100	A	
Maximum Continuous Body Diode Forward Current (N		ls	2.7	A	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			lsм	100	А
Avalanche Current, L = 0.1mH			las	19.8	A
Avalanche Energy, L = 0.1mH			E <sub>AS</sub>	19.6	mJ

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	1.0	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	124	°C/W
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	PD	2.1	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>0JA</sub>	61	°C/W
Thermal Resistance, Junction to Case (Note 6)	Rejc	6.2	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

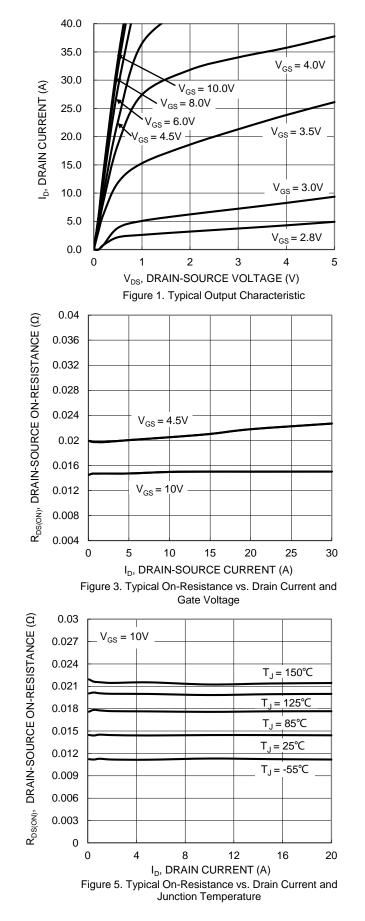
<u>Ob eventerintic</u>	Cumphiel	Min	True	May	11	Test Condition	
	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)		40	r				
Drain-Source Breakdown Voltage	BVDSS	40			V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	_	-	1	μA	V <sub>DS</sub> = 32V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	lgss	—	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)					-	1	
Gate Threshold Voltage	VGS(TH)	1	—	3	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Bacati		14.7	19	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	Rds(on)		21.2	29	11152	VGS = 4.5V, ID = 15A	
Diode Forward Voltage	Vsd		1.0	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		750		pF		
Output Capacitance	Coss		225	—	pF	− V <sub>DS</sub> = 20V, V <sub>GS</sub> = 0V, − f = 1MHz	
Reverse Transfer Capacitance	Crss	_	21	_	pF		
Gate Resistance	Rg	_	1.1	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg		5.7	_	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg		11.2	—	nC		
Gate-Source Charge	Q <sub>gs</sub>		2.0	—	nC	$V_{DS} = 20V, I_{D} = 20A$	
Gate-Drain Charge	Q <sub>gd</sub>		2.2	—	nC		
Turn-On Delay Time	tD(ON)	_	3.5	_	ns		
Turn-On Rise Time	t <sub>R</sub>	_	4.6	_	ns	$V_{GS} = 10V, V_{DD} = 20V,$ $R_g = 1.6\Omega, I_D = 20A$	
Turn-Off Delay Time	tD(OFF)	_	12.4	_	ns		
Turn-Off Fall Time	tF		4.9		ns		
Body Diode Reverse Recovery Time	trr		11.3	—	ns		
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	_	9.5		nC	l⊧ = 15A, di/dt = 400A/µs	

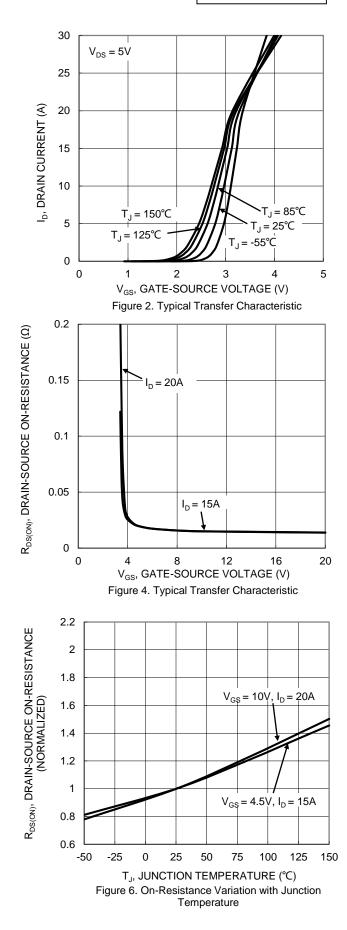
Notes:

Device mounted on FR-4 PCB, with minimum recommended pad layout, single sided.
Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



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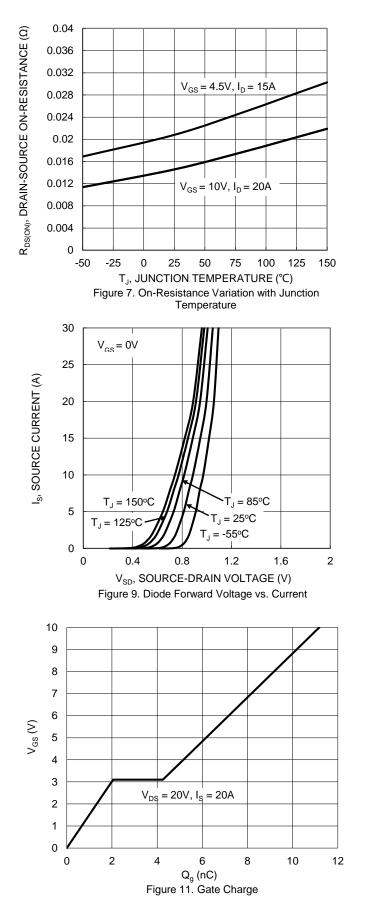


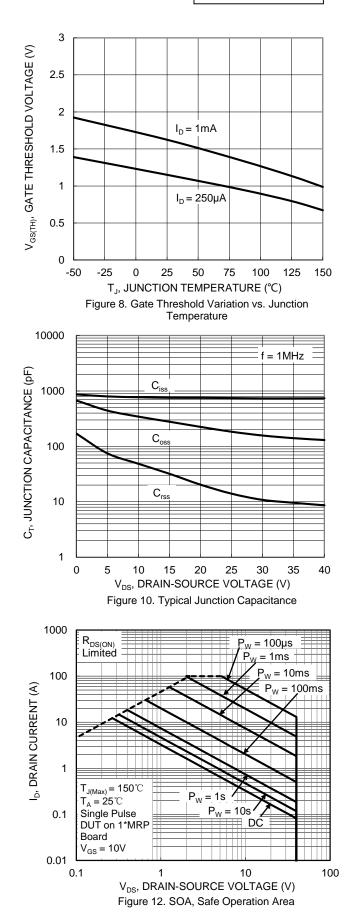


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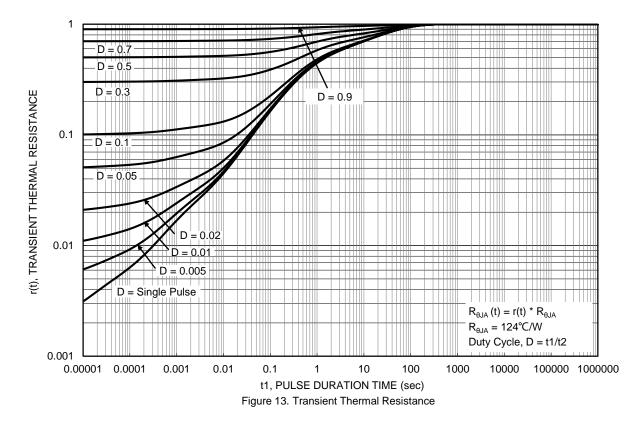


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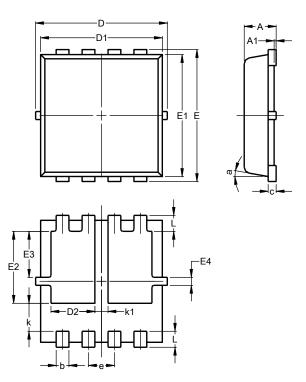






# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

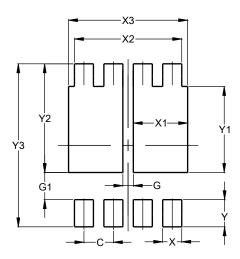


PowerDI3333-8 (Type UXC)					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05			
b	0.25	0.40	0.32		
С	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	0.90	1.30	1.10		
Е	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E3	0.95	1.35	1.15		
E4	0.10	0.30	0.20		
е	-	-	0.65		
L	0.30	0.50	0.40		
k	0.50	0.90	0.70		
k1	0.13	0.53	0.33		
а	0°	12°	10°		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8 (Type UXC)



Dimensions	Value (in mm)			
С	0.650			
G	0.230			
G1	0.600			
Х	0.420			
X1	1.200			
X2	2.370			
X3	2.630			
Y	0.600			
Y1	1.900			
Y2	2.400			
Y3	3.600			

# PowerDI3333-8 (Type UXC)



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